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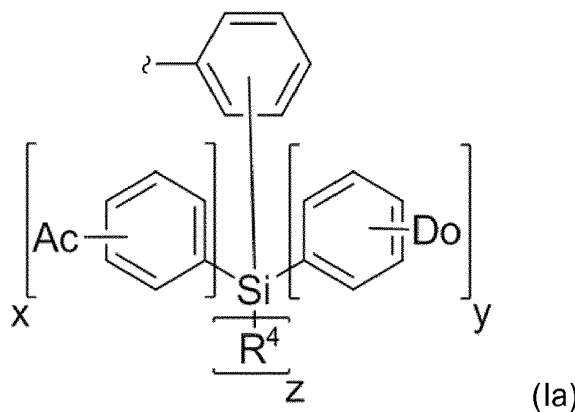
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Remarks:
Amended claims in accordance with Rule 137(2) EPC.

(54) **SILICON-BASED EMITTER COMPOUND**

(57) The present invention relates to emitter compounds E of formula (I) or salts thereof based on a triazine core, substituted with at least one moiety of formula (Ia):



and at least one donor moiety. Further, the present invention also refers to a light-emitting layer B comprising the emitter compound E and to an opto-electronic device OD comprising such light-emitting layer B. Moreover, the present invention relates to a method for generating light of a desired wavelength range by means of the opto-electronic device OD.

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